

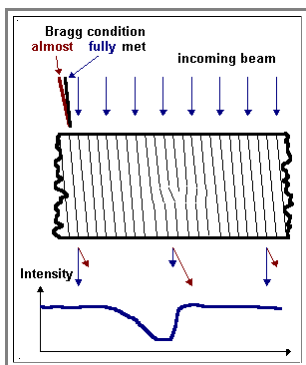
6.2 X-Ray Topography

There are no efficient lenses for **X-rays** and therefore no **X-ray** microscopes. Still, there are ways to image defects with **X-rays**.

The essential part for imaging defects in crystals is the **diffraction** of the **X-rays** in the crystal lattice. This is in contrast to the conventional **X-ray** imaging technique in medical applications where the differential **absorption** of **X-rays** in differently dense tissue is used.

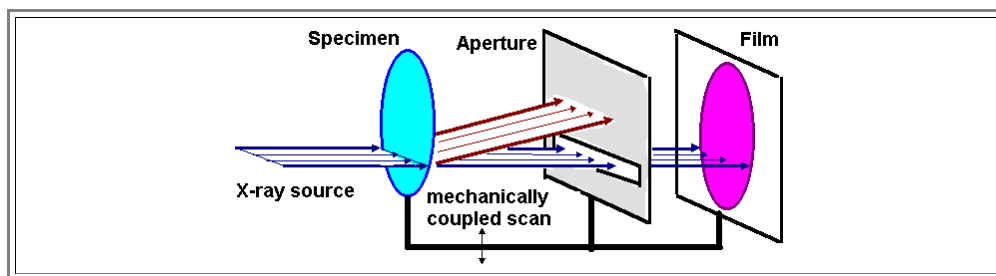
The basic principle (which is also valid for imaging with electron beams in the transmission electron microscope) is shown below:

- The specimen is oriented with respect to the incoming wave in such a way that the **Bragg-condition** for diffraction is only met (or nearly met) for just **one** set of lattice planes.
- All defects with strain fields will locally deform the lattice and thus change the Bragg condition locally. The intensity of the diffracted beam will react to this and vary around defects. This is schematically shown below



- In the example, the specimen is oriented in such a way that the Bragg condition in the perfect part of the crystal is almost, but not quite met. There will be no diffraction or, more quantitatively speaking, a rather low intensity of the diffracted beam. The primary beam thus is transmitted almost without any losses.
- To the left-hand side of the edge dislocation, the strain field bends the lattice plane locally into the Bragg position. In this area the primary beam is strongly diffracted and loses intensity.
- The intensity of the diffracted beam is mirror symmetric to the primary beam.

For the imaging of defects (typically in **Si**-wafers, with or without processing) the following basic set-up is used.



An **X-ray** source with a thin "one-dimensional" beam cross-section illuminates a line of the wafer. Only the primary beam (or, for dark-field imaging, the diffracted beam) is admitted through an aperture on the film. Wafer, aperture, and film are scanned through the beam.

Some examples of **X-ray** topography are given in the following links; [another one](#) we have already encountered before.

- [Total view and resolution limit](#)
- [Case study in bipolar technique](#)

The strengths and weaknesses of **X-ray** topography are quite apparent:

Strength	Weaknesses
<ul style="list-style-type: none"> Imaging of large wafers with good resolution (ca. 5 μm) possible Detailed analysis (e.g. Burgers vectors) possible within limits No specimen preparation necessary 	<ul style="list-style-type: none"> Very expensive rather long exposure times even with powerful (typically 50 kW) X-ray tubes Resolution/sensitivity not good enough for single/small defects